



Recovery of indium from indium tin oxide by solvent extraction

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ABSTRACT

Recovery of indium from LCD screen wastes, which contain indium in the form of indium tin oxide (ITO) as the electrode material, is becoming economically and environmentally justified. Indium is a valuable metal and the present work was aimed to recover indium from ITO as the starting material to study the recovery of indium from waste LCD screens by solvent extraction.

The apparent rate of dissolution in acidic media is slow requiring six hours for complete dissolution of the ITO sample in 1 M of either H₂SO₄ or HCl. Complete dissolution in HNO₃ took significantly longer. The acid concentration was found to have a major effect on both the amount and rate of leaching allowing some leaching selectivity.

Three solvent systems were chosen to study their selectivity for the separation of indium from tin: TBP, D2EHPA and a mixture of both. With either 1 M of TBP or 0.2 M of D2EHPA + 0.8 M of TBP, tin could be selectively extracted from a 1.5 M HCl solution of this metal. D2EHPA extracts both indium and tin from H₂SO₄ media but indium could be selectively stripped with HCl from the loaded D2EHPA. Based on these results, a scheme for separating and concentrating indium from ITO by solvent extraction is proposed. The scheme includes dissolving ITO into 1 M of H₂SO₄, then extracting indium and tin to D2EHPA followed by selective stripping of indium into 1.5 M of HCl. With this process, HCl solution containing 12.2 g/L of indium could be achieved.

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1. Introduction

Indium is a rare and valuable metal, which is used mainly as indium tin oxide-films (84% in 2007) in liquid crystal displays (LCDs) (Tolcin, 2008). These indium tin oxide (ITO) films are composed of 90% of In₂O₃ and 10% of SnO₂. New types of solar panels containing indium are being developed and they may become an important application sector for indium in the future (Tolcin, 2009) potentially increasing the demand for indium.

Indium is evenly distributed in the earth's crust. It has no minerals of its own so it has to be recovered as a byproduct from other metallurgical processes or from secondary raw materials. Most commonly indium is associated with zinc, lead, copper, and tin ores (Bailar et al., 1973; Kleinberg et al., 1960; Mineral Information Institute—INDIUM, 2010). In the 21st century, the price has been at its lowest (below 100 USD/kg) in 2002 and highest (over 1000 USD/kg) in 2005. Currently, the price is around the 535 USD/kg (MinorMetals Prices, 2010).

The largest indium producer is China with other big suppliers being South Korea, Japan, Canada, Belgium, Russia, France and Peru.

China also has by far the world's biggest indium reserves. The global refinery production of indium was 568 t in 2008 (Tolcin, 2008; Tolcin, 2009).

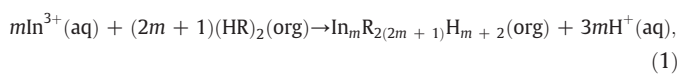
Today the amount of waste LCD screens from computer and TV sets is fast accumulating owing to the popularity of their usage particularly in consumer goods and thus, development of recovery methods for indium from these wastes is growing in importance. Since 2007 more indium has been produced from secondary than from primary raw materials. The most important secondary raw material has been the waste coming from the sputtering process in the deposition of ITO onto the LCDs, in which only 30% of ITO is deposited onto the glass surface (Tolcin, 2008; Tolcin, 2009). From the sputtering waste indium can be recovered by dissolving it in HCl and then precipitating it with NaOH (Ryoshi et al., 2008). A few methods have been patented for recovering indium from secondary ITO waste (used LCDs). The methods of Lee et al. (2007) and Chen et al. (2003) are based on leaching and precipitation. As in any precipitation techniques, these methods are limited by the solubility equilibrium of the hydroxide. Shimofusa et al. (2000) have patented a method in which indium is recovered by solvent extraction from nitric acid solution, which includes heavy metals as impurity but the use of nitric acid is expensive. Clearly, there remains a need to develop a more efficient method of recovering indium from waste LCDs.

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1.1. Solvent extraction of indium

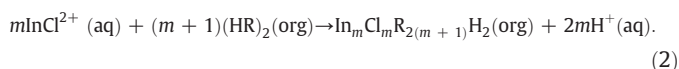
Solvent extraction is a commonly used method for the purification of indium in process metallurgy particularly in zinc refineries, where indium is usually recovered from sulfate solutions (Alfantazi and Moskalyk, 2003). The research in the solvent extraction of indium started in the early 1960s (Paiva, 2001). The earliest patents and articles about the use of solvent extraction in the hydrometallurgical recovery of indium were published in the early 1980s (Tomii and Tsuchida, 1981; Fossi and Sambarino, 1983; Ke et al., 1984). Several extractant types have been used in the extraction of indium including carboxylic acids, phosphoric acid derivatives, chelating compounds like hydroxyoximes and azoles, and solvating extractants such as tributyl phosphate (TBP), trioctylphosphine oxide (TOPO) and methyl isobutyl ketone (MIBK). See Paiva (2001) for a good review.

Bis(2-ethylhexyl) phosphate (CAS-number 298-07-7), usually known as di-2-ethylhexylphosphoric acid (D2EHPA), is by far the most popular extractant and it is almost always used in practical applications since it has a high loading capacity for indium and good selectivity for indium over many other metal ions such as, for example, Zn(II), Fe(II), Cd(II), As(III) and Cu(II) (Fossi and Sambarino, 1983; Ke et al., 1984; Li et al., 2006). Sato and Sato (1992) and Sato (1975) reported a comprehensive research about the extraction of indium with D2EHPA and another organophosphorus extractant, 2-ethylhexyl 2-ethylhexyl-phosphonic acid (EHEHPA), from H₂SO₄, HNO₃ and HCl solutions. They found that the extraction of indium was in the order HNO₃>H₂SO₄>HCl in acid concentrations below 2 M, but in concentrated acids, the order is reversed. According to these investigators, D2EHPA is a better extractant than EHEHPA. Sato and Sato (1992) and Sato (1975) concluded that, from sulfate media, only In³⁺ ions are extracted so the sulfate concentration has no effect on extraction. They also found that although significant complexation of indium with nitrate occur when the nitrate concentration is above 0.1 M (C_{In,tot} = 3.2 mmol/L), the complexes are not extracted with D2EHPA or EHEHPA. This indicated that, in sulfate and nitrate media, the extraction mechanism is purely ion exchange and polymeric indium species may also form. The equation for the extraction of indium in sulfate and nitrate media may be written as follows (1) (Sato and Sato, 1992; Sato, 1975):



where HR is the extractant molecule.

In chloride media the corresponding reaction is



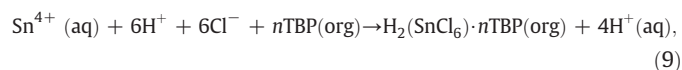
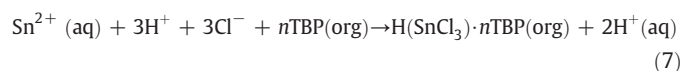
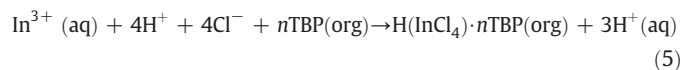
In high hydrochloric acid concentrations (>1 M) solvation mechanism also occurs:



D2EHPA may also be mixed with other known extractants, typically alkylphosphates or alkylphosphine oxides, in order to improve the selectivity of extraction and stripping (Tomii and Tsuchida, 1981; Rickelton, 1994). With other commercial extractants, some binary separations have been reported for Cyanex 923 (mixture of four trialkyl phosphineoxides) and Cyanex 272 (the active extractant is bis(2,4,4-trimethylpentyl)phosphinic acid), but they both have lower loading capacity for indium than D2EHPA (Gupta et al., 2004, 2007).

Although there are several articles on the solvent extraction of indium using D2EHPA, very few of them considered the effect of tin when present in solution with indium. One such study was that of Nikov et al. (1994) who attempted to recover indium from smelting

residues. They found that tin is co-extracted with indium when using D2EHPA and that it was necessary to use TBP to separate them. Levin et al. (1967) on the other hand stated that extraction of tin(IV) is much slower than the extraction of indium suggesting that the different kinetics could be exploited in separating these metals. Tomii and Tsuchida (1981) mentioned in their patent that the mixture of D2EHPA and TBP has some In/Sn selectivity. In an earlier study, Golinski (1971) found out that TBP has good selectivity for tin over indium from HCl media. He proposed the following equations for the extraction of indium and tin in HCl media using TBP:



where n=2 or 3. He stated that at HCl concentrations below 2 M extraction follows Eqs. (4), (6) and (8) while at high HCl concentrations Eqs. (5), (7) and (9).

The purpose of the present study was to explore the most appropriate experimental conditions for the acidic leaching of ITO and then use solvent extraction with D2EHPA, TBP and their mixtures as extractants to separate and concentrate indium from its acidic solutions.

2. Experimental

2.1. Reagents

The following reagents were used in this study: indium tin oxide (ITO) nano powder (Inframat Advanced Materials, 99.99%, particle size 30–70 nm) in the leaching experiments; <44 μm ITO (Sigma-Aldrich) as starting material. The extractants were diluted with ShellSol 2046, also known as narrow cut kerosene, (Shell Chemicals) or Exxsol D-80; D2EHPA (BDH Laboratory Supplies, assay 98% and Baysolvex); TBP (Ajax Finechem, assay 99% and Aldrich, assay 97%); sulfuric, nitric and hydrochloric acids. All acids were of pro analysis purity.

2.2. Analytical techniques

All metal analyses of aqueous samples were carried out using ICP-AES.

2.3. Leaching and dissolution

For the study of the leaching of ITO, the dissolution experiments were carried out in a glass reactor by agitating 1 g of ITO with 1 L of 0.1 and 1.0 M HCl, HNO₃ and H₂SO₄ for 18 to 24 h. A two-bladed plastic impeller was used with a rotating speed of 545 rpm. In addition, batch experiments were done by shaking 0.1 g of ITO nano powder for 30 h

with 100 mL of acids of different concentrations (0.001, 0.01, 0.1, and 1 M).

The D2EHPA was washed with 6 M HCl and distilled water before use while the TBP was pretreated with 1 M NaOH and distilled water before use.

2.4. Solvent extraction

Three different extractant compositions were used in the solvent extraction experiments: 1 M D2EHPA, 1 M TBP and a mixture of 0.2 M D2EHPA + 0.8 M TBP. The equilibrium experiments were carried out in either conical flasks or separatory funnels and the equilibrating time was at least 30 min. The ITO test solutions were obtained by dissolving ITO with L/S ratio of 1000:1 to acids. The resulting solutions contained indium (~740 mg/L) and tin (~33 mg/L or 80 mg/L in the case where ITO nano powder was used).

The effect of the initial acid concentration to the extraction equilibrium was determined for every acid (H₂SO₄, HCl and HNO₃). For the extraction with D2EHPA the selective stripping with HCl was also explored. In these experiments D2EHPA was first loaded with A/O = 5:1 from ITO nano powder solution of 1 M H₂SO₄ and then stripped with A/O = 1:1 with HCl solutions of various concentrations. The contact time for both the loading and stripping was three hours.

For D2EHPA, the loading isotherm for indium from ITO solution was constructed. Test solutions of ITO in 1 M H₂SO₄ (30 mL) were contacted for three hours with different amounts of D2EHPA. The

Table 1

Leaching and dissolution of ITO with mineral acids. L/S = 1000:1, t = 30 h. Yields of dissolution, Y_{In} and Y_{Sn}, are calculated based on the fact that the ITO sample was composed of 90% In₂O₃ and 10% of SnO₂.

c, M	c _{In} (mg/L)	c _{Sn} (mg/L)	Y _{In} (%)	Y _{Sn} (%)
<i>Sulfuric acid</i>				
0.001	35	0	5	0
0.01	330	0	44	0
0.1	822	0	100	0
1	778	91.1	100	100
<i>Nitric acid</i>				
0.001	23	0	3	0
0.01	0	0	0	0
0.1	526	4.4	69	5
1	740	16.1	100	21
<i>Hydrochloric acid</i>				
0.001	24	0	3	0
0.01	86	1.2	12	2
0.1	700	38.9	94	49
1	749	81.4	100	100

stripping isotherm for D2EHPA with 1.5 M HCl was also constructed. D2EHPA was first loaded from the ITO solution in 1 M H₂SO₄ with an A/O = 5:1 and then stripped using various phase ratios.

The fractions of extraction and stripping, E_E and E_S respectively, are defined as follows:

$$E_E = \frac{c_{0, \text{aq}} - c_{\text{aq}}}{c_{0, \text{aq}}} \cdot 100\% \quad (10)$$

$$E_S = \frac{c_{0, \text{org}} - c_{\text{org}}}{c_{0, \text{org}}} \cdot 100\% = \frac{c_{\text{aq}}}{c_{0, \text{org}}} \cdot 100\%, \quad (11)$$

where

c_{0, aq} = initial concentration of the metal in aqueous phase, mg/L

c_{aq} = equilibrium concentration of the metal in aqueous phase, mg/L

c_{0, org} = initial concentration of the metal in organic phase, mg/L

c_{org} = equilibrium concentration of the metal in organic phase, mg/L

3. Results and discussion

3.1. Leaching and dissolution

The apparent rates of the leaching kinetics of the oxide mixture in all the three acids were slow (Fig. 1) with that of nitric acid the

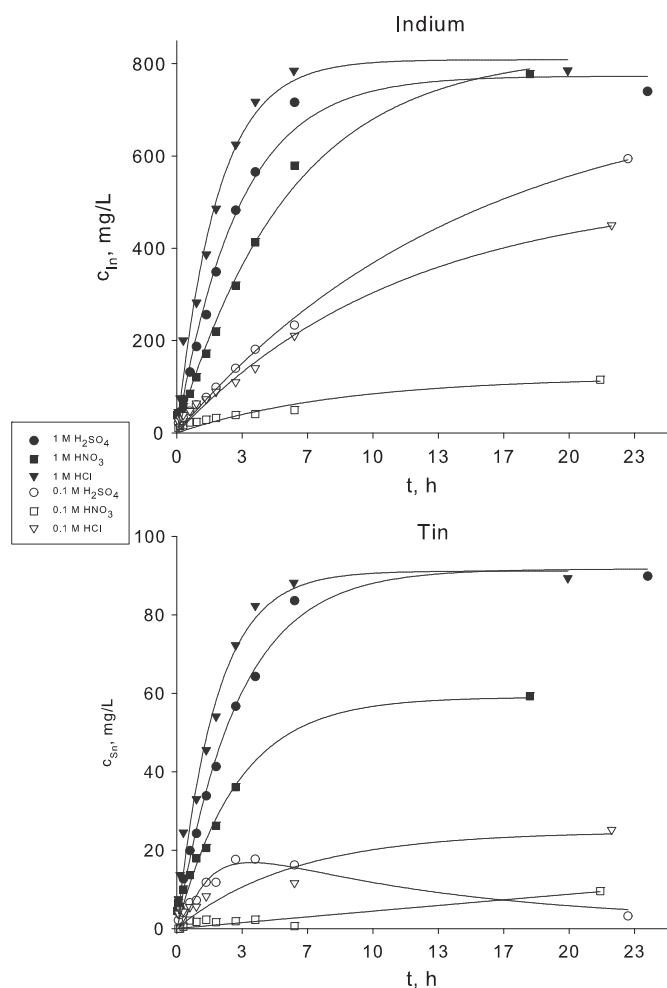


Fig. 1. Leaching of indium and tin from ITO-powder to H₂SO₄, HCl and HNO₃. L/S ratio was 1000:1.

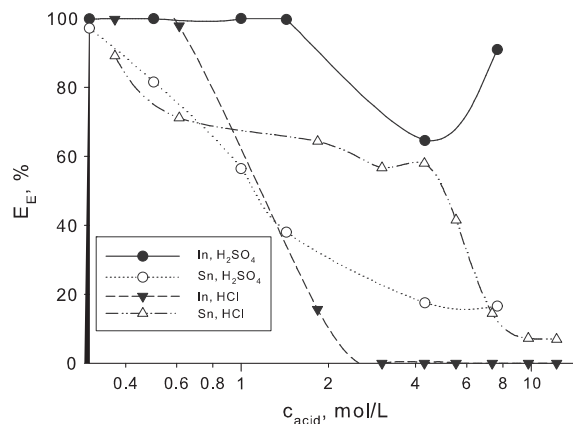


Fig. 2. Effect of initial acid concentration on extraction of indium and tin with 1 M D2EHPA. A/O = 1:1, c_{0, In} = 392...793 mg/L, c_{0, Sn} = 10...37 mg/L. Initial metal concentrations were lower at first two points compared to others due to slow dissolution of ITO.

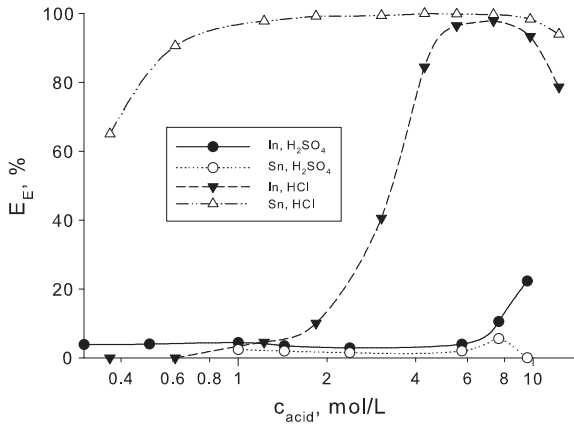


Fig. 3. Effect of initial acid concentration on extraction of indium and tin with 1 M of TBP. A/O = 1:1, $c_{0,In} \approx 700$ mg/L, $c_{0,Sn} \approx 33$ mg/L.

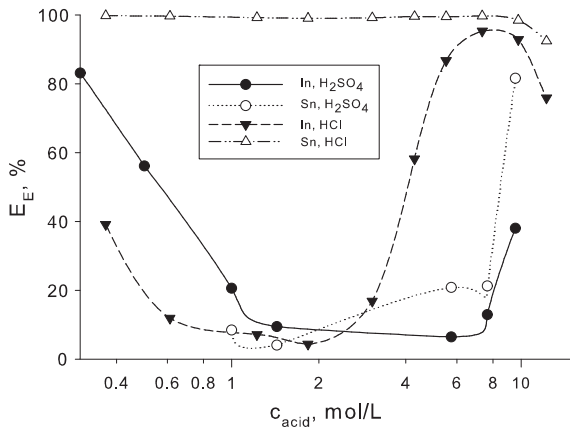


Fig. 4. Effect of initial acid concentration on extraction of indium and tin with the mixture of 0.2 M of D2EHPA and 0.8 M of TBP. A/O = 1:1, $c_{0,In} \approx 700$ mg/L, $c_{0,Sn} \approx 32$ mg/L.

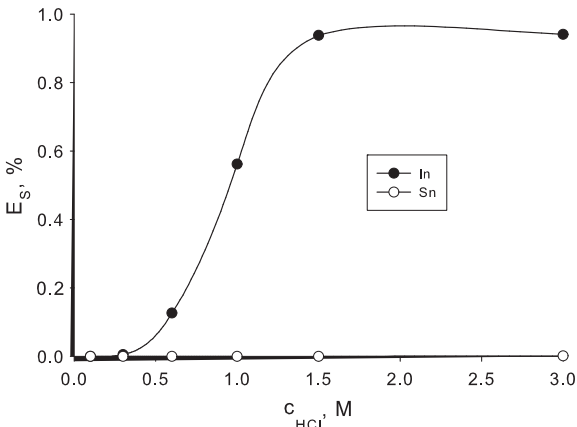


Fig. 5. Effect of initial HCl concentration on the stripping of indium and tin from 20% D2EHPA. A/O = 1:1, $c_{0,In,org} = 3.35$ g/L, $c_{0,Sn,org} = 0.26$ g/L.

slowest. A tenfold increase in acid concentration from 0.1 M acids to 1.0 M acids resulted in considerable increases in the rate of leaching. Complete dissolution of both metals, indium and tin, in 1 M H_2SO_4 and 1 M HCl was achieved in 6 h. The complete dissolution of these metals in 0.1 M acids could not be achieved even for a day (Fig. 1).

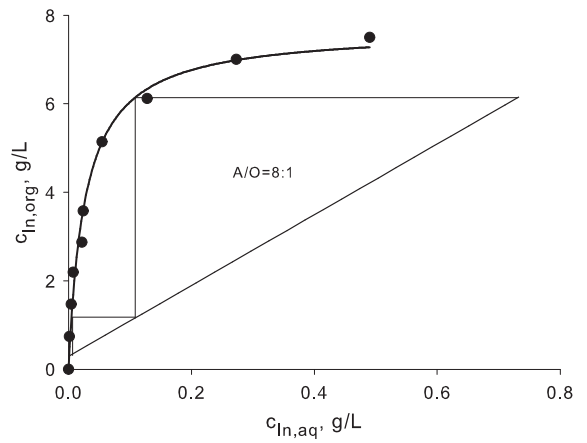


Fig. 6. McCabe–Thiele diagram for the extraction of indium with 20% D2EHPA from 1 M of H_2SO_4 .

Table 1 shows the dissolution of indium and tin in various concentrations of the three acids used. All dissolution tests were carried out for 30 h. The results show that indium and tin have slightly different solubility in different concentrations of these acids that can be exploited in separating these metals from their combined oxides. For example, there was good selectivity with 0.01 M and 0.1 M H_2SO_4 and 0.1 M and 1.0 M HNO_3 .

3.2. Solvent extraction

3.2.1. Separation of indium and tin

The separation of indium and tin by solvent extraction was studied using sample solutions of these metal ions in H_2SO_4 , HNO_3 and HCl media. Three different extractants were used: D2EHPA (1 M), TBP (1 M) and a mixture of 0.2 M D2EHPA + 0.8 M TBP. It is helpful for the purpose of this discussion of results to state at the outset that, in nitric acid media, no separation of indium and tin was achieved with any of the extractant used including the combination of D2EHPA and TBP. Also, decreasing the concentration of the extractants by tenfold had no effect on the separation of the metals with any of the acid used.

With D2EHPA, the selectivity for indium over tin was much higher particularly at the higher end of the range of acid concentration that was investigated although a minimum of 20% tin was still extracted.

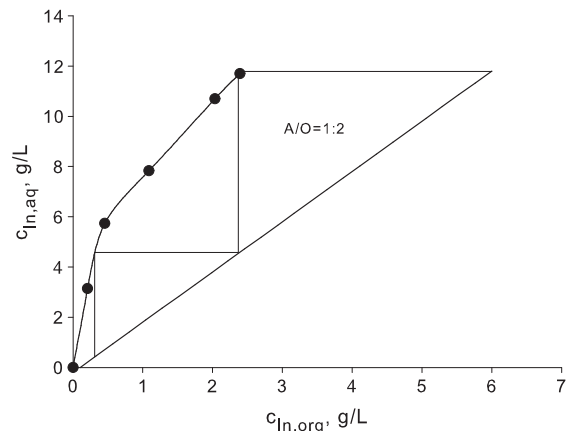


Fig. 7. McCabe–Thiele diagram for the stripping of indium from 20% D2EHPA with 1.5 M of HCl.

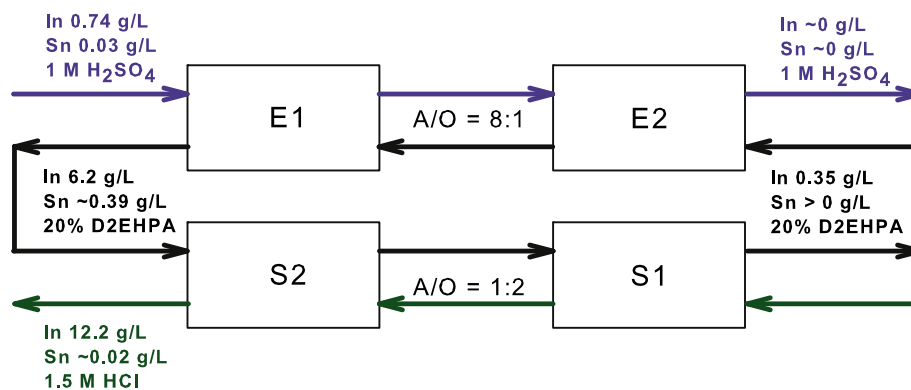


Fig. 8. Suggested flow sheet for solvent extraction recovery of indium from 1 M of H_2SO_4 containing tin as an impurity. Phase ratios are for extraction (E1 and E2) $A/O = 8:1$ and for stripping (S1 and S2) $A/O = 1:2$.

In HCl media, the tin extraction was higher than indium, but no satisfactory separation could be achieved (Fig. 2).

With TBP, tin could be extracted when the HCl concentration is above 0.3 M. At 1.2 M HCl, over 97% of tin could be extracted (Fig. 3). In contrast indium did not extract until the initial HCl concentration was above 1.0 M. A very good separation of these metals from chloride media was therefore achieved. These results are consistent with those of Golinski (1971). In H_2SO_4 media very weak extraction and low selectivity was observed.

A good separation of indium and tin from their HCl solutions (1–2 M) was also obtained when using the combination extractant (0.2 M D2EHPA + 0.8 M TBP) (Fig. 4). Around 5% of indium, however, was co-extracted so the resulting loaded organic solution would need to be treated further. It is expected minimal co-extraction of indium in organic load in the continuous extraction. This metal can be separated in the stripping step or by scrubbing.

Another way of achieving separation between indium and tin was by selective stripping of the loaded D2EHPA with HCl. As shown in Fig. 5, no tin was stripped over the entire range of acid concentration investigated while 94% stripping efficiency for indium was achieved with HCl concentrations of 1.5 M and above.

3.2.2. McCabe–Thiele analysis

D2EHPA is known to have very good loading capacity for indium from 1 M sulfuric acid (Fossi and Sambarino, 1983). In our experiments (Fig. 6), when the equilibrium concentration in aqueous phase was 0.49 g/L, the distribution coefficient was 15.3 and full loading was still not achieved. For tin, the loading capacity was found to be around 0.39 g/L.

Based on extraction and stripping stages described below (Figs. 6 and 7), a scheme for solvent extraction unit operation is given (Fig. 8). The McCabe–Thiele plot in Fig. 6 shows indium extraction with two countercurrent stages with $A/O = 8:1$. Analysis of data indicated that 6.2 g/L of indium containing organic phase can be achieved starting from 0.74 g/L of aqueous solution with recovery of indium over 99%. Corresponding analysis was also done for the stripping of the loaded D2EHPA with 1.5 M HCl. According to the McCabe–Thiele plot, a 6.2 g of In/L loaded D2EHPA can be stripped to 0.35 g/L with $A/O = 1:2$ in two countercurrent stages (Fig. 7). This yielded an HCl strip solution containing 12.2 g/L of indium. The maximum concentration of tin in these stripping solutions was 0.022 g/L. Under these conditions of metal ion concentrations, indium may be recovered by cementation (Nikov et al., 1994).

4. Conclusions

The present work showed that, in terms of leaching, the apparent rates of dissolution of indium tin oxide (ITO) in acidic media were

slow but best achieved with either H_2SO_4 or HCl as the apparent dissolution rates in these acids are comparable and faster than that in HNO_3 . Given that H_2SO_4 is less corrosive to process equipment than HCl, it has a slight advantage over the latter. The apparent rate of dissolution of ITO increases with increases in acid concentration and the acid concentration may be exploited to achieve some selectivity of dissolution.

In terms of separation and purification of the dissolved indium and tin, three different solvent extraction systems were studied for separation of these metals. Tin could be selectively extracted from its HCl solutions with either 1 M of TBP or with a mixture of 0.2 M of D2EHPA and 0.8 M of TBP. With both solvent systems, the HCl concentration that yielded optimal extraction was around 1.5 M. Another way was to extract both metals from their H_2SO_4 solutions with D2EHPA and then selectively strip indium with >1.5 M of HCl. This route of selective stripping is the most attractive because D2EHPA has a very high loading capacity for indium (7.5 g/L in 0.49 g/L of aqueous concentration). McCabe–Thiele analysis of this solvent system revealed that with two countercurrent stages ($A/O = 1:8$) of extraction and two countercurrent stages ($A/O = 2:1$) of stripping, indium could be concentrated from 0.74 g/L to 12.2 g/L and almost complete indium recovery from the leaching solution and high In/Sn selectivity in stripping could be achieved. These results show that solvent extraction is an effective method of concentrating indium and separating it from tin and therefore applicable for recovering indium from ITO.

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